

COMPOUND FIELD EFFECT POWER TRANSISTOR

μ PA1560

N-CHANNEL POWER MOS FET ARRAY SWITCHING INDUSTRIAL USE

DESCRIPTION

The μ PA1560 is N-Channel Power MOS FET Array that built in 4 circuits designed for solenoid, motor and lamp driver.

FEATURES

- Full mold package with 4 circuits
- · 4 V driving is possible
- Low on-state resistance

 $R_{DS(on)1}$ = 165 $m\Omega$ MAX. (Vgs = 10 V, Ip = 1.5 A)

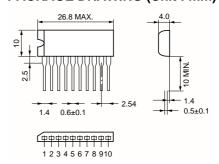
 $R_{DS(on)2} = 200 \text{ m}\Omega$ MAX. (Vgs = 4 V, ID = 1.5 A)

 Low input capacitance C_{iss} = 600 pF TYP.

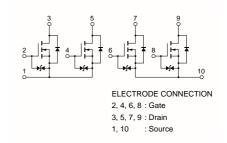
ORDERING INFORMATION

PART NUMBER	PACKAGE
μ PA1560H	10-pin SIP

PACKAGE DRAWING (Unit: mm)



EQUIVALENT CIRCUIT



ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Vss = 0 V)	Voss	120	V
Gate to Source Voltage (VDS = 0 V)	VGSS(AC)	±20	V
Gate to Source Voltage (VDS = 0 V)	VGSS(DC)	+ 20, -10	V
Drain Current (DC)	ID(DC)	±3.0	Α
Drain Current (pulse) Note1	ID(pulse)	±12	Α
Total Power Dissipation (Tc = 25°C)	P _{T1}	28	W
Total Power Dissipation (T _A = 25°C)	P _{T2}	3.7	W
Channel Temperature	Tch	150	°C
Storage Temperature	T_{stg}	-55 to + 150	°C
Single Avalanche Current Note2	IAS	3.0	Α
Single Avalanche Energy Note2	Eas	0.9	mJ

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1 %

2. Starting T_{ch} = 25 °C, V_{DD} = 60 V, R_G = 25 Ω , V_{GS} = 20 V \rightarrow 0 V

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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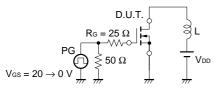
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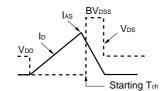


ELECTRICAL CHARACTERISTICS (TA = 25 °C)

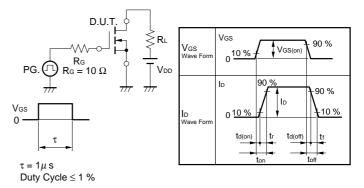
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CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain to Source On-state Resistance	RDS(on)1	Vgs = 10 V, ID = 1.5 A		130	165	mΩ
	R _{DS(on)2}	Vgs = 4.0 V, Ip = 1.5 A		145	200	mΩ
Gate to Source Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1.0 mA	1.0	1.8	2.5	V
Forward Transfer Admittance	yfs	V _{DS} = 10 V, I _D = 1.5 A	2	4.5		S
Drain Leakage Current	Ipss	V _{DS} = 120 V, V _{GS} = 0 V			10	μΑ
Gate to Source Leakage Current	Igss	Vgs = ±20 V, Vps = 0 V			±10	μΑ
Input Capacitance	Ciss	V _{DS} = 10 V		600		pF
Output Capacitance	Coss	V _G S = 0 V		160		pF
Reverse Transfer Capacitance	Crss	f = 1.0 MHz		70		pF
Turn-on Delay Time	td(on)	ID = 1.5 A		35		ns
Rise Time	tr	VGS(on) = 10 V		80		ns
Turn-off Delay Time	td(off)	VDD = 60 V		700		ns
Fall Time	tf	$R_L = 30 \Omega$		250		ns
Total Gate Charge	QG	ID = 3.0 A		28		nC
Gate to Source Charge	Qgs	V _{DD} = 96 V		2.5		nC
Gate to Drain Charge	Q _{GD}	Vgs = 10 V		9		nC
Body Diode Forward Voltage	V _F (S-D)	IF = 3.0 A, VGS = 0 V		0.9		V
Reverse Recovery Time	trr	IF = 3.0 A, VGS = 0 V		160		ns
Reverse Recovery Charge	Qır	$di/dt = 50 A/ \mu s$		280		nC

TEST CIRCUIT 1 AVALANCHE CAPABILITY

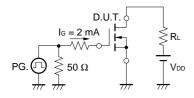




TEST CIRCUIT 2 SWITCHING TIME



TEST CIRCUIT 3 GATE CHARGE



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